

CIWC-2
2020

2nd Coatings and Interfaces Web Conference

15–31 May 2020

Chaired by Dr. Alessandro Lavacchi, Prof. Dr. Andriy Voronov

Surface X-Ray Diffraction study of a bi-layer junction based on
Cu and Cd sulphides for photovoltaic applications

Tommaso Baroni*, Francesco Di Benedetto, Andrea Giaccherini, Enrico Berretti,
Francesca Russo, Annalisa Guerri, Massimo Innocenti, Francesco Carlà, Roberto Felici

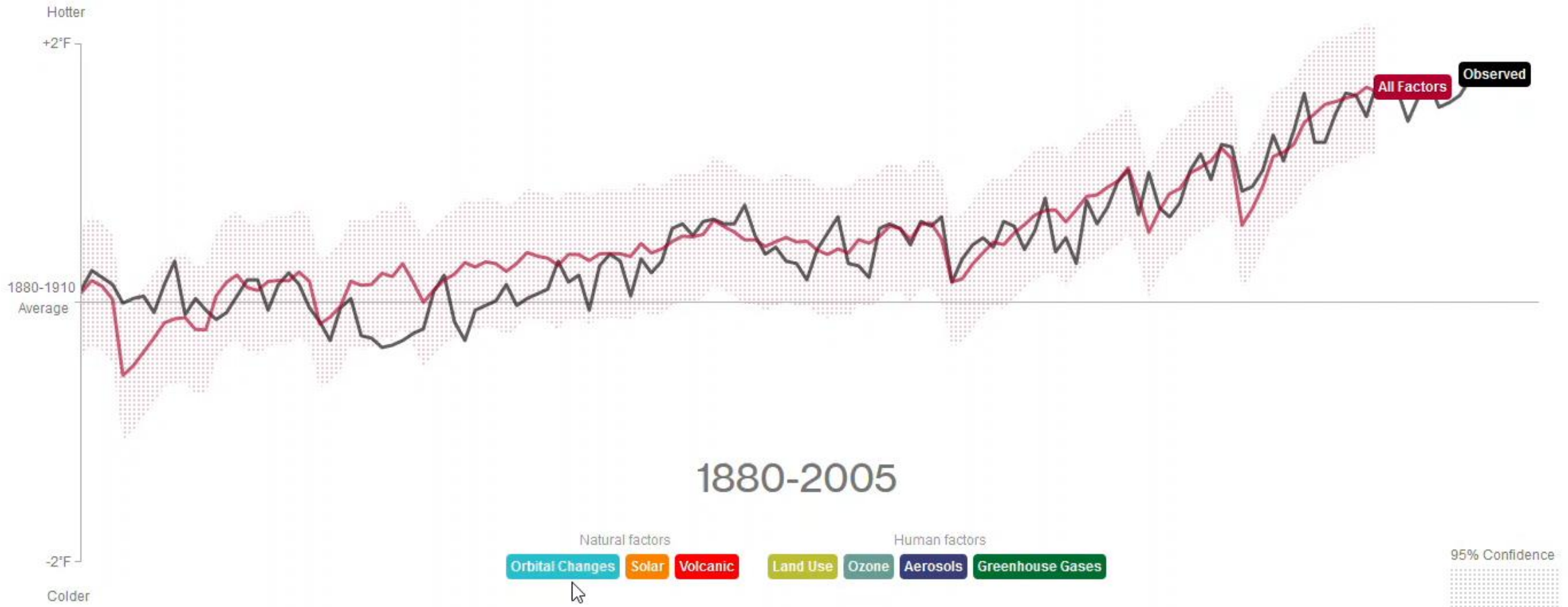
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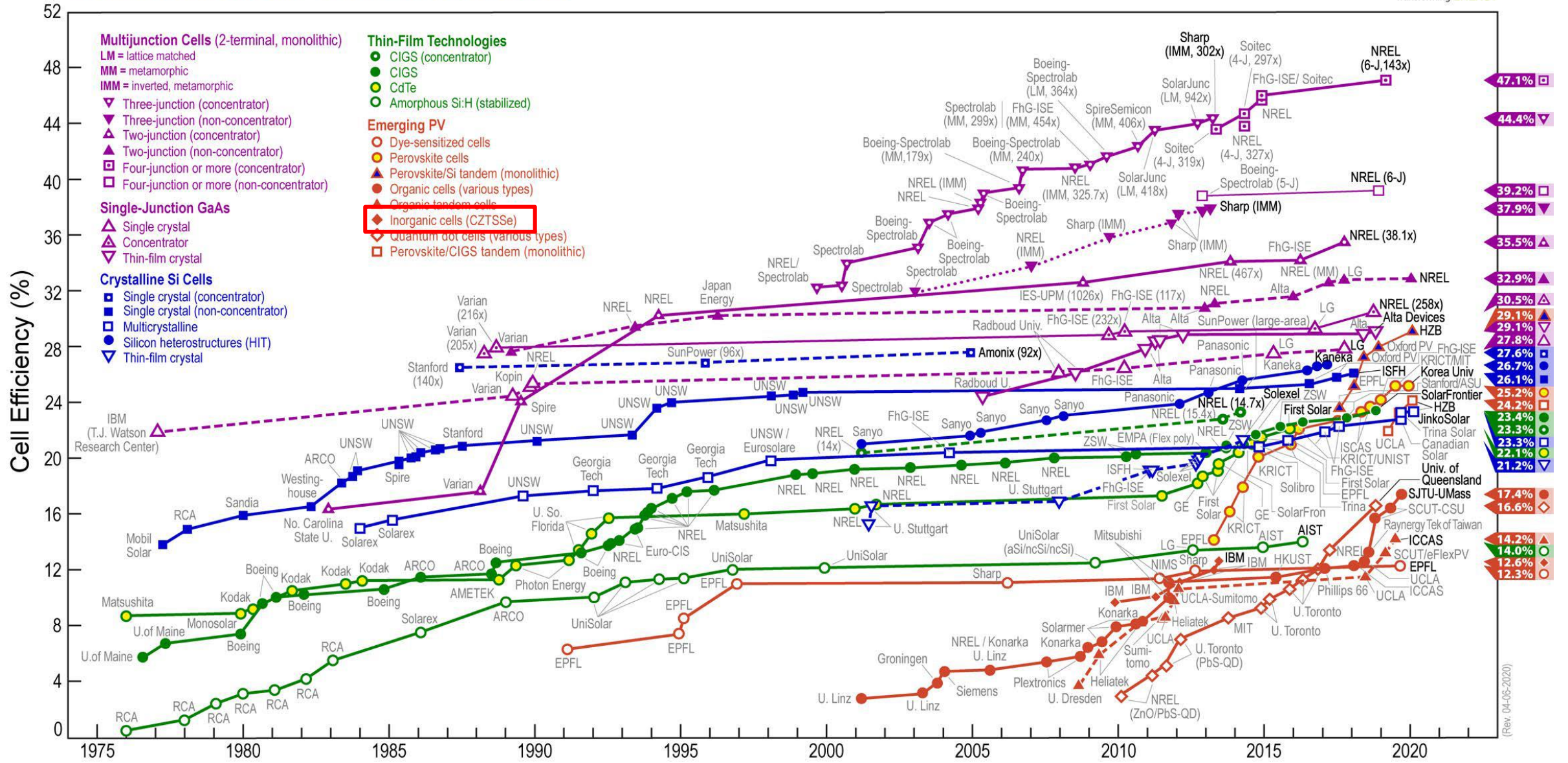
coatings



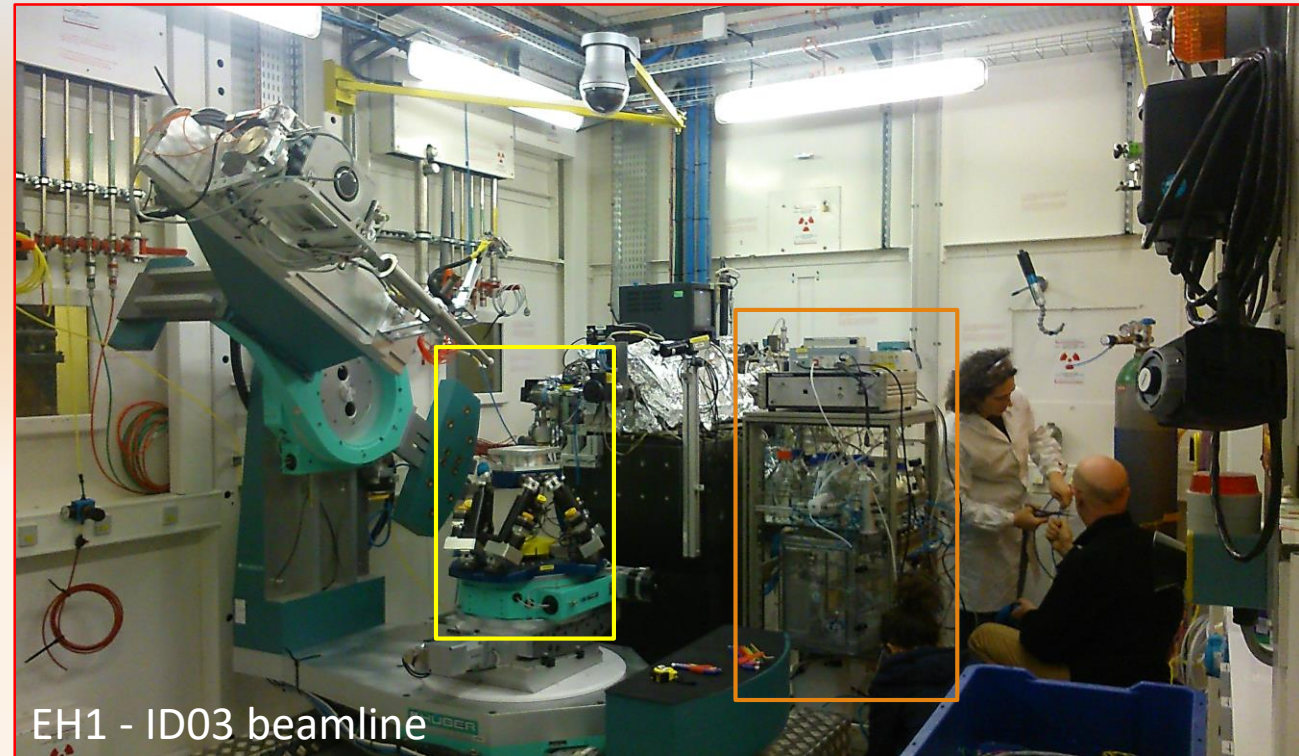
'What's really warming the world'



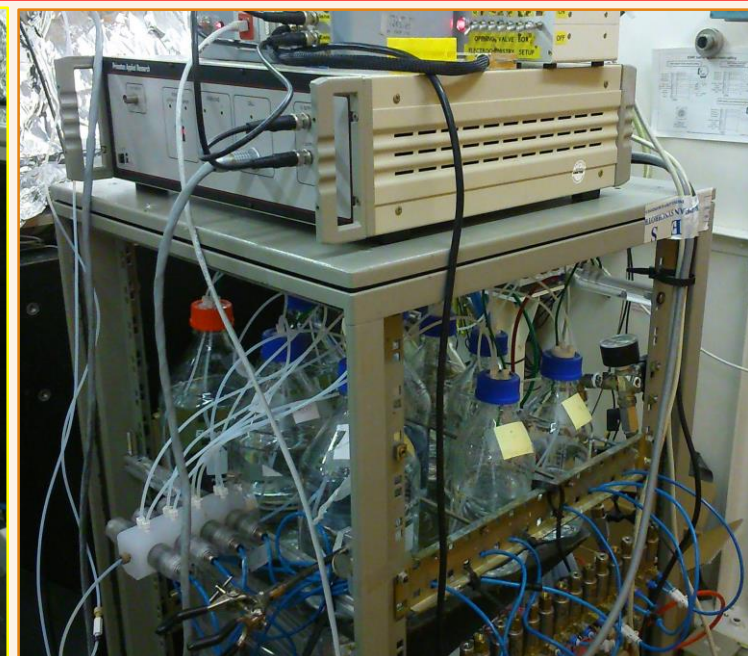
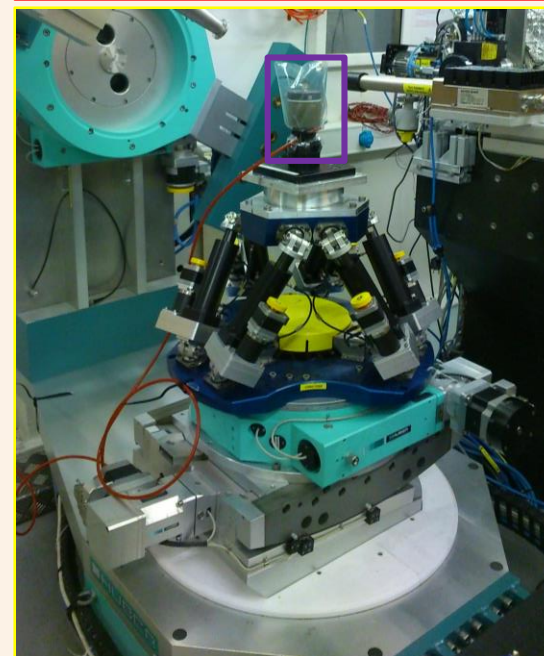
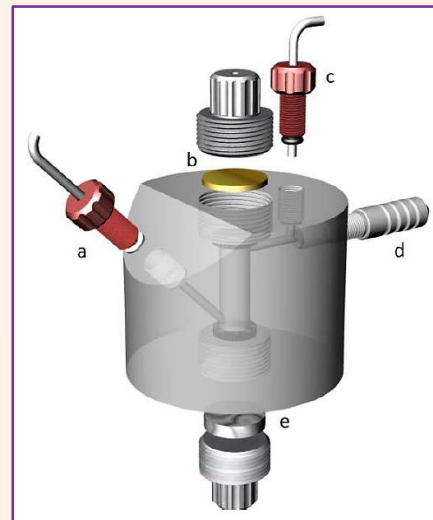
Best Research-Cell Efficiencies



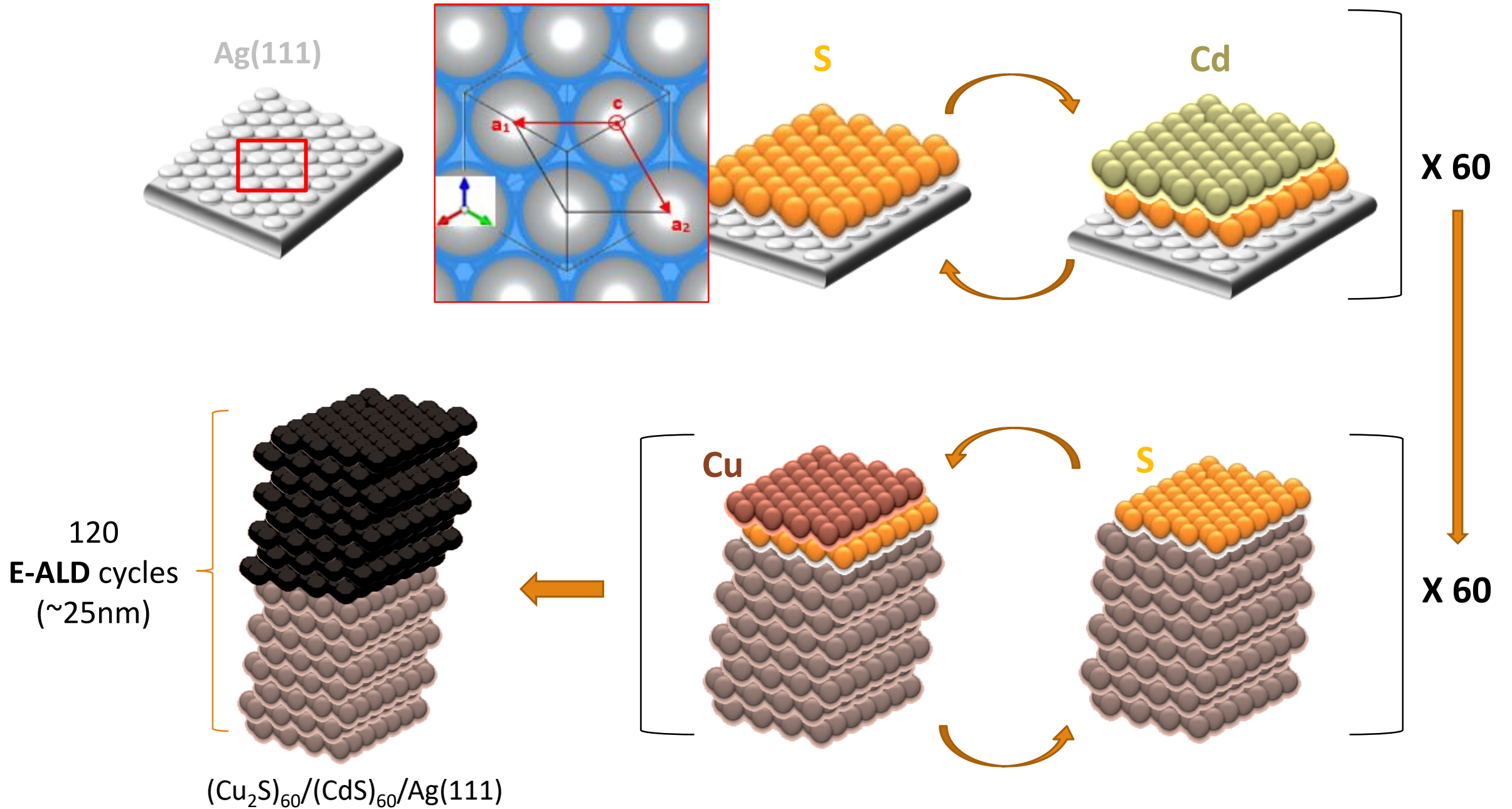
(Rev. 04-06-2020)



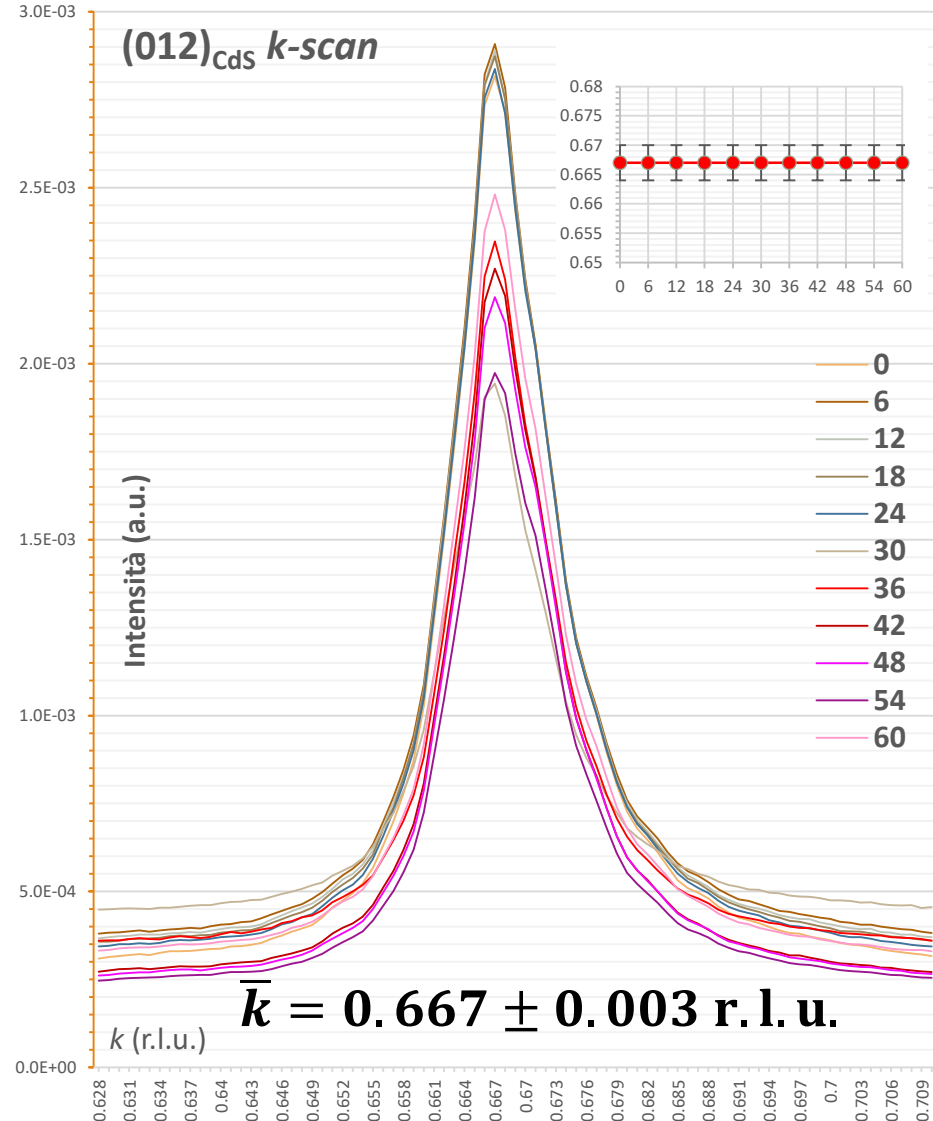
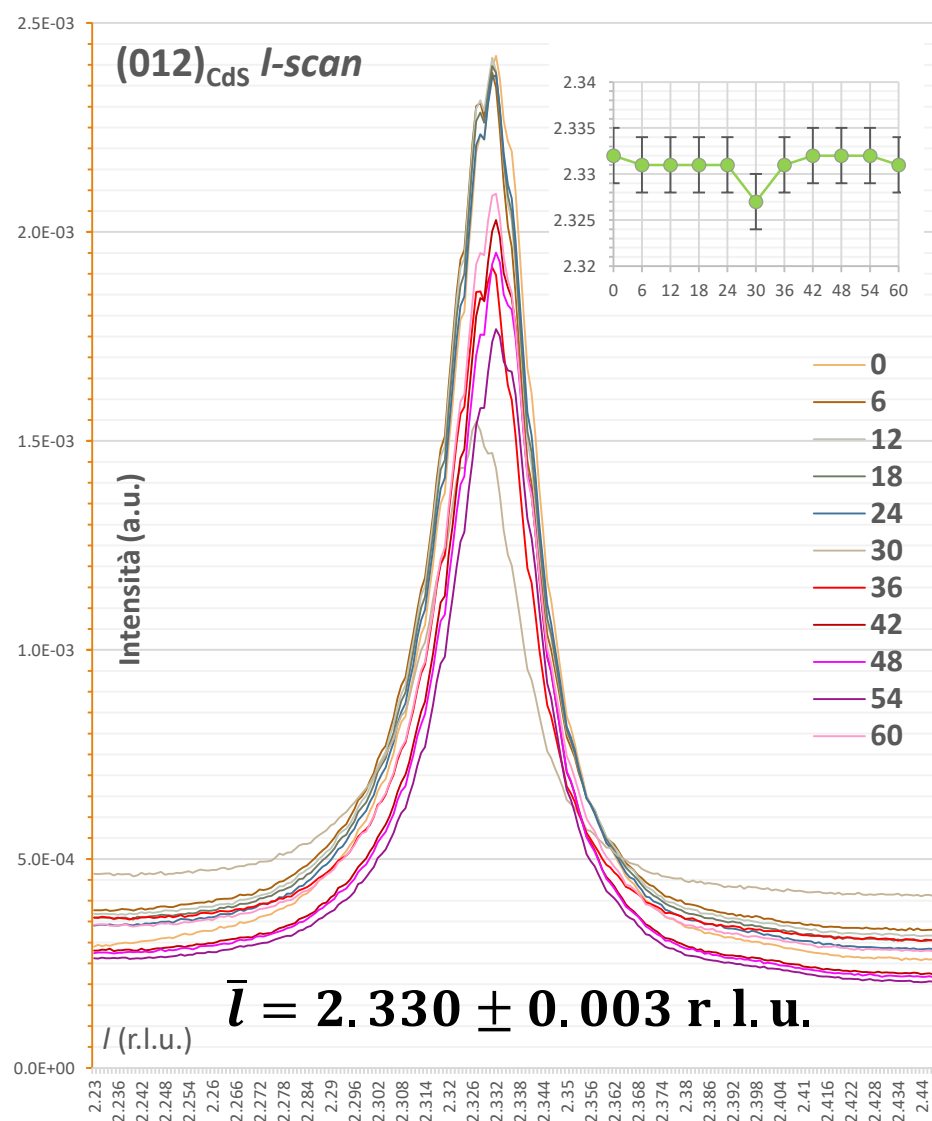
EH1 - ID03 beamline



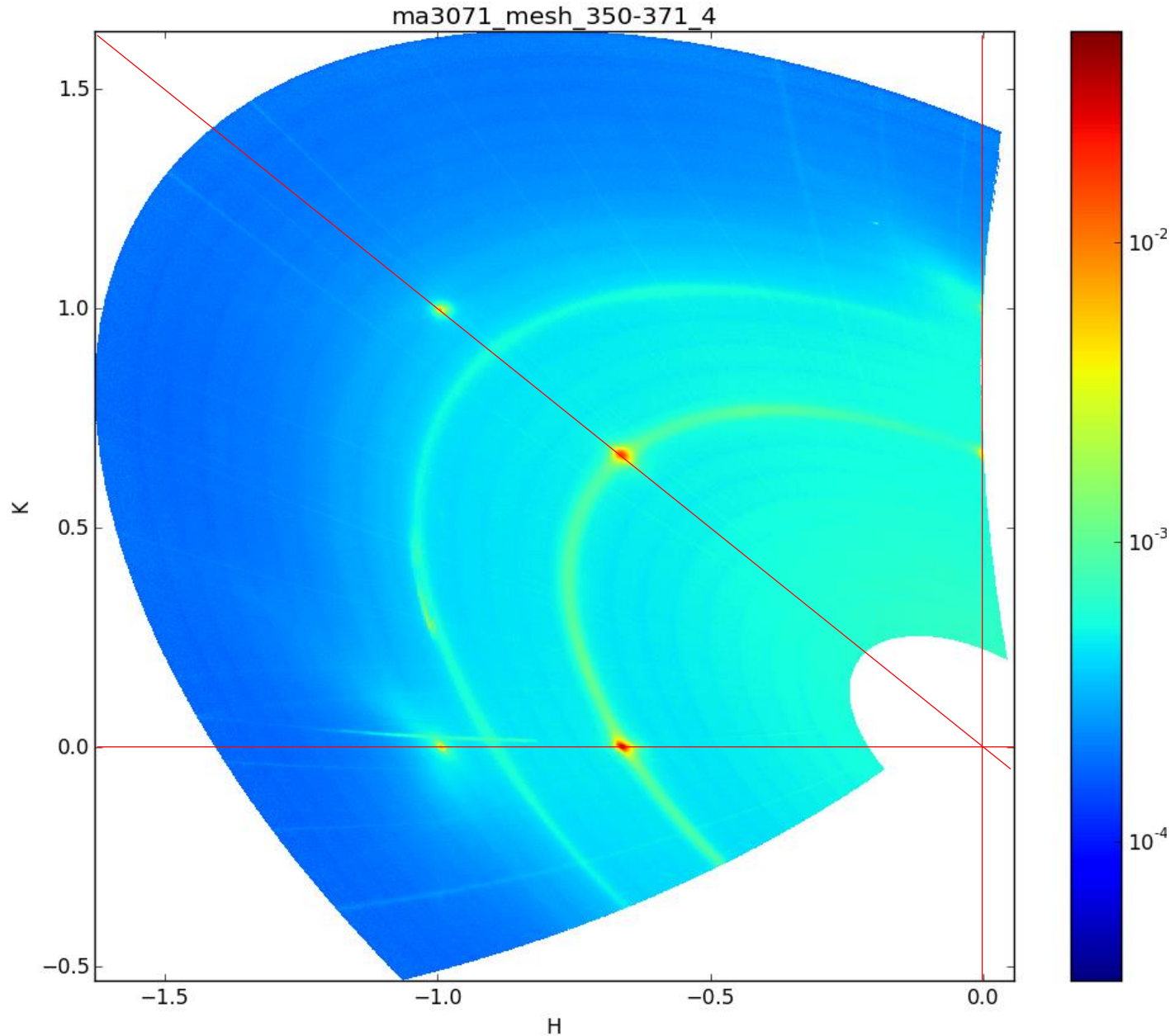
Sample preparation



(CdS)₆₀/Ag(111) structure vs N° Cu₂S cycle



(CdS)₆₀/Ag(111) 2-D BINoculars map



Greenockite

P6₃mc

$$a = b = 4.137 \text{ \AA}; c = 6.714 \text{ \AA}$$

$$\alpha = \beta = 90^\circ; \gamma = 120^\circ$$

$$V = 99.52 \text{ \AA}^3$$

(CdS)₆₀/Ag(111)

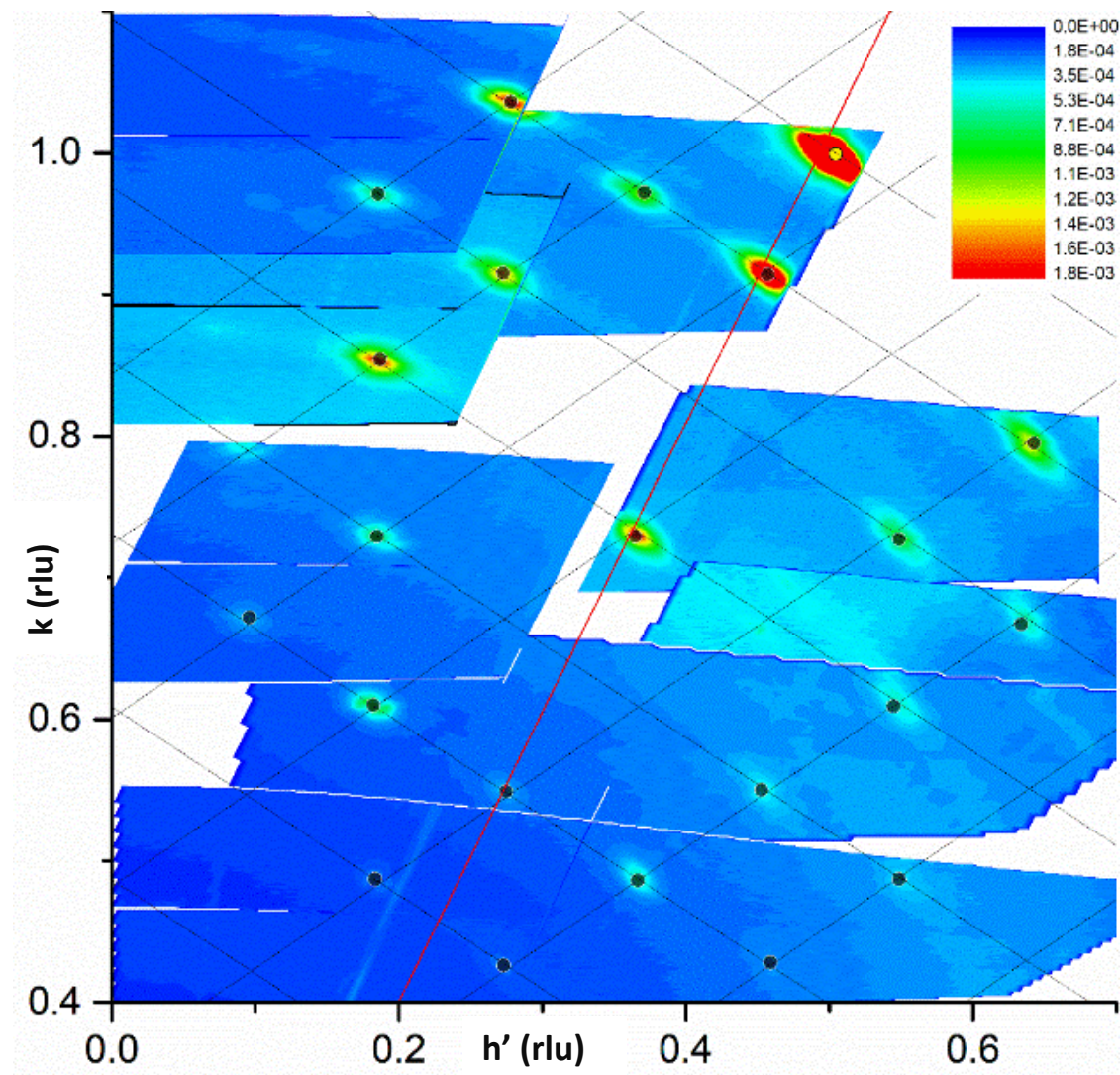
?

$$a = b = 4.332 \text{ \AA}; c = 6.075 \text{ \AA}$$

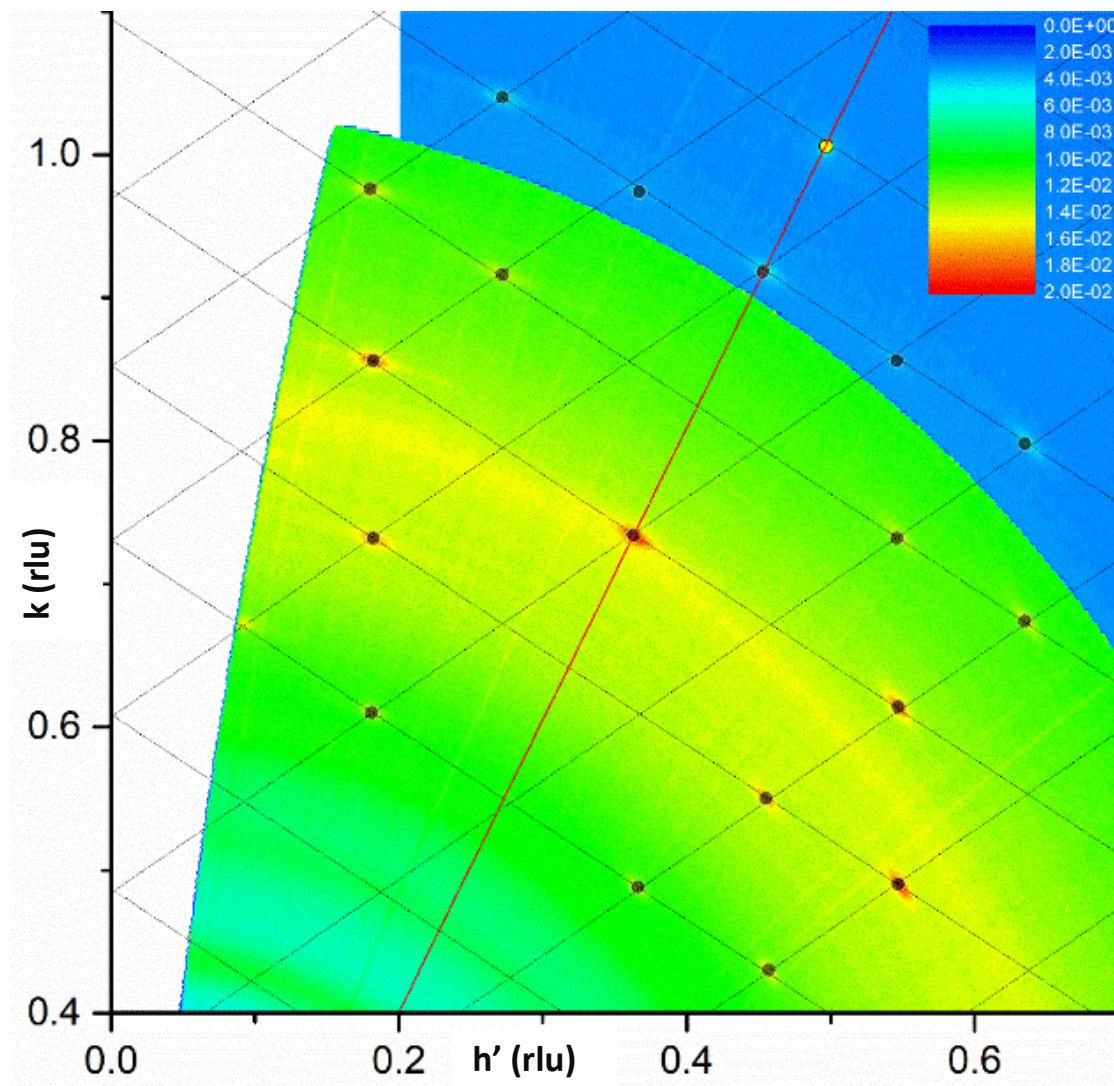
$$\alpha = \beta = 90^\circ; \gamma = 120^\circ$$

$$V = 98.73 \pm 0.37 \text{ \AA}^3$$

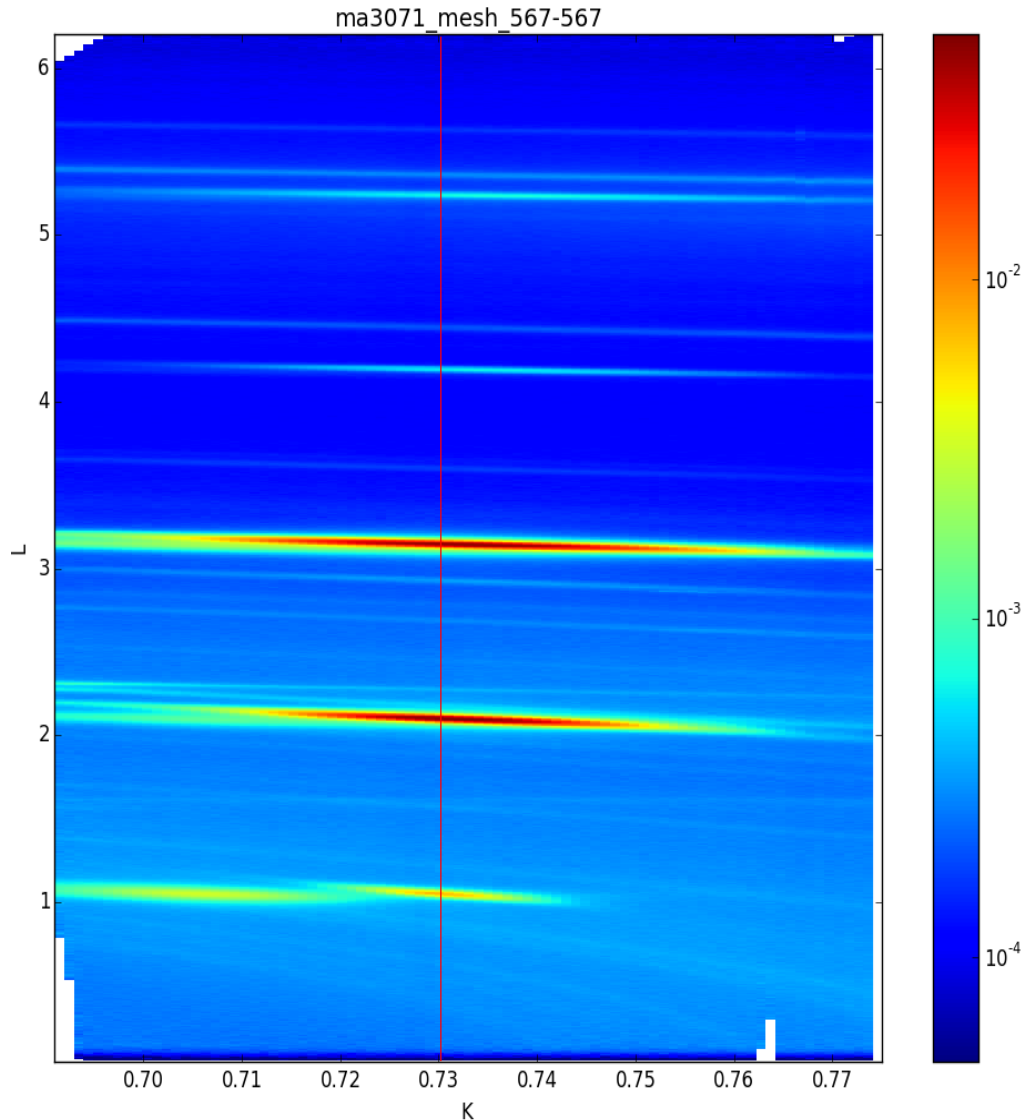
$(\text{Cu}_2\text{S})_{60}/(\text{CdS})_{60}/\text{Ag}(111)$
(MA3071)



$(\text{Cu}_2\text{S})_{60}/\text{Ag}(111)$
(ma2082)



$(0\ 0.73\ 0.2-6)_{\text{Cu}_2\text{S}}$ *I*-scan and Cu_2S cell parameters



$$a = b = 27.41 \pm 0.04 \text{ \AA}; c = 6.76 \pm 0.03 \text{ \AA}$$

$$\alpha = \beta = 90^\circ; \gamma = 120^\circ$$

$$c_{\text{chalcocite}} = 13.494 \text{ \AA}$$

Conclusions

- MA3071 is the first *in-situ* SXRD experiment which features an E-ALD bi-layer junction of $\text{Cu}_2\text{S}/\text{CdS}/\text{Ag}(111)$.
- The SXRD *in-situ* analysis highlights the profound epitaxial relationship existing between the films and the bulk, consequent to the homogenisation of the metrics of the CdS and the Cu_2S structures to values commensurate to the surface periodicity of the substrate.
- The $(\text{CdS})_{60}/\text{Ag}(111)$ develops an elementary cell with crystallographic axes parallel to those of the surface cell of the Ag(111); the comparison with the structure of greenockite suggests a compensation mechanism related to the strain imposed by the film growth on the crystallographic Ag(111) surface.
- The positions in the reciprocal space of the Cu_2S reflections is compatible with an pseudo-hexagonal pattern rotated by 30° with respect to the surface cell cell of the substrate; the data suggest a hexagonal chalcocite-like structure with a planarization of the S layers, as a result of the strong epitaxial relationship existing with the CdS below and as already noticed in relation to a $\text{Cu}_2\text{S}/\text{Ag}(111)$ E-ALD deposit by Giaccherini et al. (1).
- This study confirms E-ALD as an energy efficient method for the growth of semiconducting heterostructures with tailored properties using low cost/environmental-impact materials.